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PLASTIC MEDIUM-POWER

COPPLEMENTARY SILICON TRANSISTORS

...designed for general-purpose amplifier and low speed switching applications

FEATURES:

- * Collector-Emitter Sustaining Voltage -
 $V_{CEO(\text{min})} = 60 \text{ V (Min)} - \text{TIP120, TIP125}$
 $= 80 \text{ V (Min)} - \text{TIP121, TIP126}$
 $= 100 \text{ V (Min)} - \text{TIP122, TIP127}$
- * Collector-Emitter Saturation Voltage
 $V_{CE(\text{sat})} = 2.0 \text{ V (Max.) @ } I_C = 3.0 \text{ A}$
- * Monolithic Construction with Built-in Base-Emitter Shunt Resistor

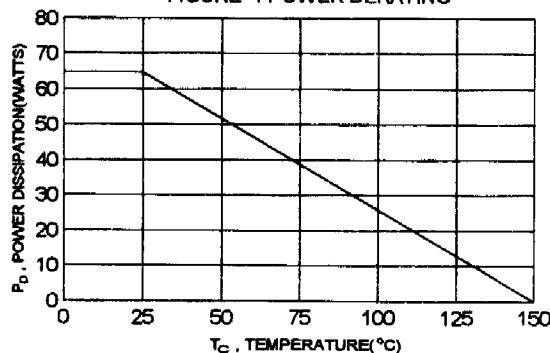
MAXIMUM RATINGS

Characteristic	Symbol	TIP120 TIP125	TIP121 TIP126	TIP122 TIP127	Unit
Collector-Emitter Voltage	V_{CEO}	60	80	100	V
Collector-Base Voltage	V_{CBO}	60	80	100	V
Emitter-Base Voltage	V_{EBO}		5.0		V
Collector Current-Continuous -Peak	I_C I_{CM}		5.0 8.0		A
Base Current	I_B		120		mA
Total Power Dissipation @ $T_c = 25^\circ\text{C}$ Derate above 25°C	P_D		65 0.52		W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{STG}		- 65 to +150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

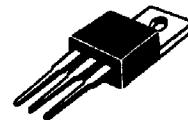
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	R_{JC}	1.92	$^\circ\text{C/W}$

FIGURE -1 POWER DERATING

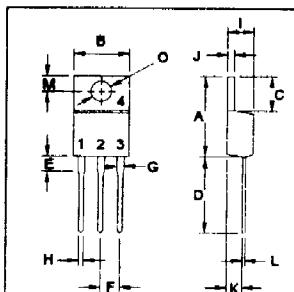


NPN	PNP
TIP120	TIP125
TIP121	TIP126
TIP122	TIP127

5.0 AMPERE
DARLINGTON
COMPLEMENTARY SILICON
POWER TRANSISTORS
60-100 VOLTS
65 WATTS



TO-220



PIN 1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR(CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.31
B	9.78	10.42
C	5.01	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	3.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90

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TIP120, TIP121, TIP122 NPN / TIP125, TIP126, TIP127 PNP

ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector - Emitter Sustaining Voltage (1) ($I_c = 30 \text{ mA}, I_b = 0$)	TIP120,TIP125 TIP121,TIP126 TIP122,TIP127	$V_{CEO(\text{sus})}$	60 80 100	V
Collector Cutoff Current ($V_{ce} = 30 \text{ V}, I_b = 0$)	TIP120,TIP125	I_{CEO}		mA
($V_{ce} = 40 \text{ V}, I_b = 0$)	TIP121,TIP126		0.5	
($V_{ce} = 50 \text{ V}, I_b = 0$)	TIP122,TIP127		0.5	
Collector Cutoff Current ($V_{ce} = 60 \text{ V}, I_b = 0$)	TIP120,TIP125	I_{CBO}		mA
($V_{ce} = 80 \text{ V}, I_b = 0$)	TIP121,TIP126		0.2	
($V_{ce} = 100 \text{ V}, I_b = 0$)	TIP122,TIP127		0.2	
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}, I_c = 0$)		I_{ESO}	2.0	mA

ON CHARACTERISTICS (1)

DC Current Gain ($I_c = 0.5 \text{ A}, V_{ce} = 3.0 \text{ V}$) ($I_c = 3.0 \text{ A}, V_{ce} = 3.0 \text{ V}$)	h_{FE}	1000 1000		
Collector-Emitter Saturation Voltage ($I_c = 3.0 \text{ A}, I_b = 12 \text{ mA}$) ($I_c = 5.0 \text{ A}, I_b = 20 \text{ mA}$)	$V_{CE(\text{sat})}$		2.0 4.0	V
Base-Emitter On Voltage ($I_c = 3.0 \text{ A}, V_{ce} = 3.0 \text{ V}$)	$V_{BE(\text{on})}$		2.5	V

DYNAMIC CHARACTERISTICS

Small-Signal Current Gain ($I_c = 3.0 \text{ A}, V_{ce} = 4.0 \text{ V}, f = 1.0 \text{ MHz}$)	h_{fe}	4.0		
Output Capacitance ($V_{cb} = 10 \text{ V}, I_e = 0, f = 0.1 \text{ MHz}$)	C_{ob}		300 250	pF

(1) Pulse Test: Pulse width = 300 μs , Duty Cycle $\leq 2.0\%$

